

TOSHIBA FIELD EFFECT TRANSISTOR SILICON N CHANNEL MOS TYPE (L<sup>2</sup>-π-MOSV)

# 2SK2614

HIGH SPEED, HIGH CURRENT SWITCHING APPLICATIONS  
 CHOPPER REGULATOR, DC-DC CONVERTER AND MOTOR DRIVE APPLICATIONS

INDUSTRIAL APPLICATIONS

Unit in mm

- 4V Gate Drive
- Low Drain-Source ON Resistance :  $R_{DS(ON)} = 0.032\Omega$  (Typ.)
- High Forward Transfer Admittance :  $|Y_{fs}| = 8S$  (Typ.)
- Low Leakage Current :  $I_{DSS} = 100\mu A$  (Max.)  
( $V_{DS} = 50V$ )
- Enhancement-Mode :  $V_{th} = 0.8 \sim 2.0V$   
( $V_{DS} = 10V, I_D = 1mA$ )

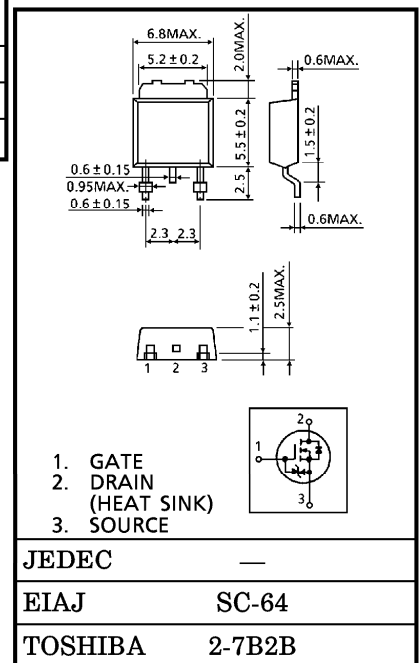
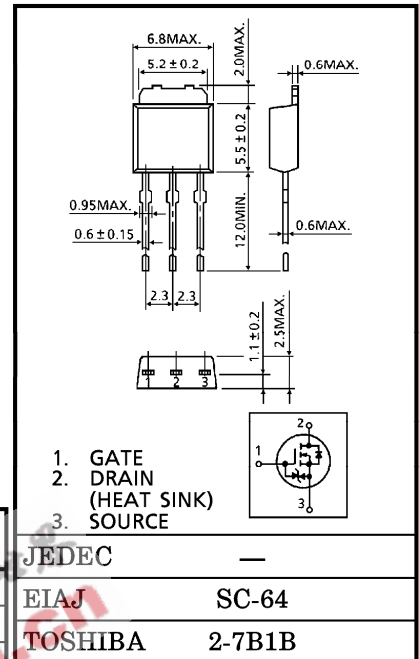
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Drain-Source Voltage		$V_{DSS}$	50	V
Drain-Gate Voltage ( $R_{GS} = 20k\Omega$ )		$V_{DGR}$	50	V
Gate-Source Voltage		$V_{GSS}$	$\pm 20$	V
Drain Current	DC	$I_D$	20	A
	Pulse	$I_{DP}$	50	A
Drain Power Dissipation (Tc = 25°C)		$P_D$	40	W
Channel Temperature		$T_{ch}$	150	°C
Storage Temperature Range		$T_{stg}$	-55~150	°C

THERMAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNIT
Thermal Resistance, Channel to Case	$R_{th(ch-c)}$	3.125	°C/W
Thermal Resistance, Channel to Ambient	$R_{th(ch-a)}$	125	°C/W

**This transistor is an electrostatic sensitive device.  
 Please handle with caution.**



Weight : 0.36g

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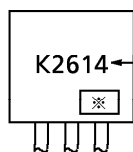
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		$I_{GSS}$	$V_{GS} = \pm 16V, V_{DS} = 0V$	—	—	$\pm 10$	$\mu A$
Drain Cut-off Current		$I_{DSS}$	$V_{DS} = 50V, V_{GS} = 0V$	—	—	100	$\mu A$
Drain-Source Breakdown Voltage		$V_{(BR) DSS}$	$I_D = 10mA, V_{GS} = 0V$	50	—	—	V
Gate Threshold Voltage		$V_{th}$	$V_{DS} = 10V, I_D = 1mA$	0.8	—	2.0	V
Drain-Source ON Resistance		$R_{DS(ON)}$	$V_{GS} = 4V, I_D = 5A$	—	0.055	0.08	$\Omega$
			$V_{GS} = 10V, I_D = 10A$	—	0.032	0.046	
Forward Transfer Admittance		$ Y_{fs} $	$V_{DS} = 10V, I_D = 10A$	7	13	—	S
Input Capacitance		$C_{iss}$	$V_{DS} = 10V, V_{GS} = 0V, f = 1MHz$	—	900	—	pF
Reverse Transfer Capacitance		$C_{rss}$		—	130	—	
Output Capacitance		$C_{oss}$		—	370	—	
Switching Time	Rise Time	$t_r$		—	15	—	ns
	Turn-on Time	$t_{on}$		—	25	—	
	Fall Time	$t_f$		—	30	—	
	Turn-off Time	$t_{off}$		—	100	—	
Total Gate Charge (Gate-Source Plus Gate-Drain)		$Q_g$	$V_{DD} = 40V, V_{GS} = 10V, I_D = 20A$	—	25	—	nC
Gate-Source Charge		$Q_{gs}$		—	19	—	
Gate-Drain ("Miller") Charge		$Q_{gd}$		—	6	—	

SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Continuous Drain Reverse Current	$I_{DR}$	—	—	—	20	A
Pulse Drain Reverse Current	$I_{DRP}$	—	—	—	50	A
Diode Forward Voltage	$V_{DSF}$	$I_{DR} = 20A, V_{GS} = 0V$	—	—	-1.7	V
Reverse Recovery Time	$t_{rr}$	$I_{DR} = 20A, V_{GS} = 0V$	—	60	—	ns
Reverse Recovery Charge	$Q_{rr}$	$dI_{DR} / dt = 50A / \mu s$	—	45	—	$\mu C$

MARKING



TYPE

※ Lot Number



Month (Starting from Alphabet A)



Year (Last Number of the Christian Era)